

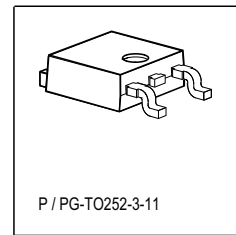


### Features

- Logic Level Input
- Input Protection (ESD)
- Thermal shutdown
- Green product (RoHS compliant)
- Overload protection
- Short circuit protection
- Overvoltage protection
- Current limitation
- Analog driving possible

### Product Summary

Drain source voltage	$V_{DS}$	42	V
On-state resistance	$R_{DS(on)}$	28	m $\Omega$
Nominal load current	$I_{D(Nom)}$	4.6	A
Clamping energy	$E_{AS}$	3.5	J

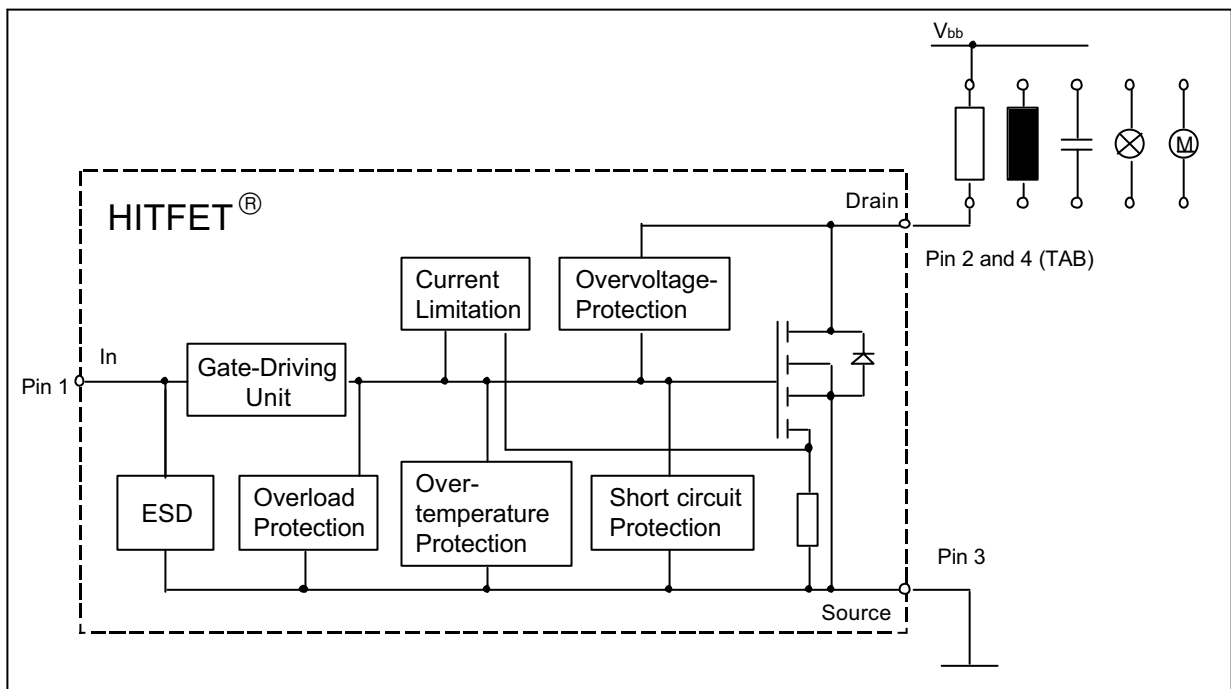


### Application

- All kinds of resistive, inductive and capacitive loads in switching or linear applications
- $\mu$ C compatible power switch for 12 V DC applications
- Replaces electromechanical relays and discrete circuits

### General Description

N channel vertical power FET in Smart SIPMOS<sup>®</sup> technology. Fully protected by embedded protection functions.



**Maximum Ratings at  $T_j = 25\text{ °C}$ , unless otherwise specified <sup>1)</sup>**

Parameter	Symbol	Value	Unit
Drain source voltage	$V_{DS}$	42	V
Drain source voltage for short circuit protection $T_j = -40 \dots +150\text{ °C}$	$V_{DS(SC)}$	28	
Continuous input current $-0.2V \leq V_{IN} \leq 10V$ $V_{IN} < -0.2V$ or $V_{IN} > 10V$	$I_{IN}$	no limit $ I_{IN}  \leq 2$	mA
Operating temperature	$T_j$	$-40 \dots +150$	$^{\circ}\text{C}$
Storage temperature	$T_{stg}$	$-55 \dots +150$	
Power dissipation <sup>4)</sup> $T_C = 85\text{ °C}$ 6cm <sup>2</sup> cooling area, $T_A = 85\text{ °C}$	$P_{tot}$	59 1.1	W
Unclamped single pulse inductive energy <sup>1)</sup>	$E_{AS}$	3.5	J
Load dump protection $V_{LoadDump}^{2)} = V_A + V_S$ $V_{IN} = 0$ and $10\text{ V}$ , $t_d = 400\text{ ms}$ , $R_l = 2\text{ }\Omega$ , $R_L = 3\text{ }\Omega$ , $V_A = 13.5\text{ V}$	$V_{LD}$	67.5	V
Electrostatic discharge voltage (Human Body Model) according to ANSI/ESDA/JEDEC JS-001 (1.5 k $\Omega$ , 100 pF)	$V_{ESD}$	2	kV

**Thermal resistance**

junction - case:	$R_{thJC}$	1.1	K/W
SMD: junction - ambient @ min. footprint @ 6 cm <sup>2</sup> cooling area <sup>3)</sup>	$R_{thJA}$	115 55	

<sup>1)</sup> Not subject to production test, specified by design.

<sup>2)</sup>  $V_{Loaddump}$  is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839

<sup>3)</sup> Device on 50mm\*50mm\*1.5mm epoxy PCB FR4 with 6cm<sup>2</sup> (one layer, 70 $\mu\text{m}$  thick) copper area for drain connection. PCB mounted vertical without blown air.

<sup>4)</sup> Not subject to production test, calculated by  $R_{thJA}/R_{thJC}$  and maximum allowed junction temperature

**Electrical Characteristics**

Parameter at $T_j = 25\text{ °C}$ , unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
<b>Characteristics</b>					
Drain source clamp voltage $T_j = -40 \dots +150\text{ °C}$ , $I_D = 10\text{ mA}$	$V_{DS(AZ)}$	42	-	55	V
Off-state drain current $T_j = -40 \dots +150\text{ °C}$ $V_{DS} = 32\text{ V}$ , $V_{IN} = 0\text{ V}$	$I_{DSS}$	-	1.5	20	$\mu\text{A}$
Input threshold voltage $I_D = 2.4\text{ mA}$ , $T_j = 25\text{ °C}$ $I_D = 2.4\text{ mA}$ , $T_j = 150\text{ °C}$	$V_{IN(th)}$	1.3 0.8	1.7 -	2.2 -	V
On state input current	$I_{IN(on)}$	-	10	30	$\mu\text{A}$
On-state resistance $V_{IN} = 5\text{ V}$ , $I_D = 4.6\text{ A}$ , $T_j = 25\text{ °C}$ $V_{IN} = 5\text{ V}$ , $I_D = 4.6\text{ A}$ , $T_j = 150\text{ °C}$	$R_{DS(on)}$	- -	27 54	34 68	$\text{m}\Omega$
On-state resistance $V_{IN} = 10\text{ V}$ , $I_D = 4.6\text{ A}$ , $T_j = 25\text{ °C}$ $V_{IN} = 10\text{ V}$ , $I_D = 4.6\text{ A}$ , $T_j = 150\text{ °C}$	$R_{DS(on)}$	- -	23 46	28 56	
Nominal load current <sup>1)</sup> $T_j < 150\text{ °C}$ , $V_{IN} = 10\text{ V}$ , $T_A = 85\text{ °C}$ , SMD <sup>2)</sup>	$I_{D(Nom)}$	4.6	-	-	A
Nominal load current <sup>1)</sup> $V_{IN} = 10\text{ V}$ , $V_{DS} = 0.5\text{ V}$ , $T_C = 85\text{ °C}$ , $T_j < 150\text{ °C}$	$I_{D(ISO)}$	12.6	-	-	
Current limit (active if $V_{DS} > 2.5\text{ V}$ ) <sup>3)</sup> $V_{IN} = 10\text{ V}$ , $V_{DS} = 12\text{ V}$ , $t_m = 200\text{ }\mu\text{s}$	$I_{D(lim)}$	30	45	55	

<sup>1</sup> Not subject to production test, calculated by  $R_{thJA}/R_{thJC}$  and  $R_{DS(on)}$

<sup>2</sup> @  $6\text{ cm}^2$  cooling area

<sup>3</sup> Device switched on into existing short circuit (see diagram Determination of  $I_{D(lim)}$ ). If the device is in on condition and a short circuit occurs, these values might be exceeded for max.  $50\text{ }\mu\text{s}$ .

**Electrical Characteristics**

Parameter at $T_j = 25\text{ °C}$ , unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	

**Dynamic Characteristics**

Turn-on time $V_{IN}$ to 90% $I_D$ : $R_L = 4.7\ \Omega$ , $V_{IN} = 0$ to 10 V, $V_{bb} = 12$ V	$t_{on}$	-	60	120	$\mu\text{s}$
Turn-off time $V_{IN}$ to 10% $I_D$ : $R_L = 4.7\ \Omega$ , $V_{IN} = 10$ to 0 V, $V_{bb} = 12$ V	$t_{off}$	-	60	120	
Slew rate on 70 to 50% $V_{bb}$ : $R_L = 4.7\ \Omega$ , $V_{IN} = 0$ to 10 V, $V_{bb} = 12$ V	$-dV_{DS}/dt_{on}$	-	0.3	1.5	V/ $\mu\text{s}$
Slew rate off 50 to 70% $V_{bb}$ : $R_L = 4.7\ \Omega$ , $V_{IN} = 10$ to 0 V, $V_{bb} = 12$ V	$dV_{DS}/dt_{off}$	-	0.3	1.5	

**Protection Functions<sup>1)</sup>**

Thermal overload trip temperature	$T_{jit}$	150	175	-	$^{\circ}\text{C}$
Input current protection mode	$I_{IN(Prot)}$	-	220	400	$\mu\text{A}$
Input current protection mode $T_j = 150\text{ °C}$	$I_{IN(Prot)}$	-	180	400	
Unclamped single pulse inductive energy <sup>2)</sup> $I_D = 4.6$ A, $T_j = 25\text{ °C}$ , $V_{bb} = 12$ V	$E_{AS}$	3.5	-	-	J

**Inverse Diode**

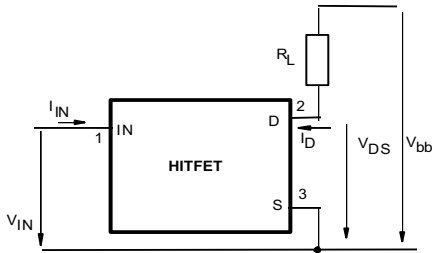
Inverse diode forward voltage $I_F = 51$ A, $t_m = 250\ \mu\text{s}$ , $V_{IN} = 0$ V, $t_P = 300\ \mu\text{s}$	$V_{SD}$	-	1.0	-	V
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<sup>1)</sup>Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

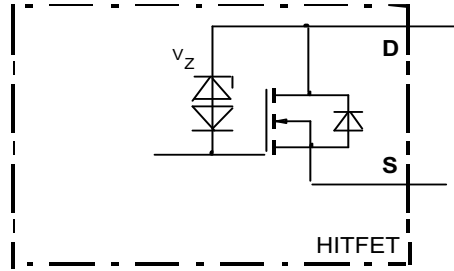
<sup>2)</sup> Not tested, specified by design.

## Block diagram

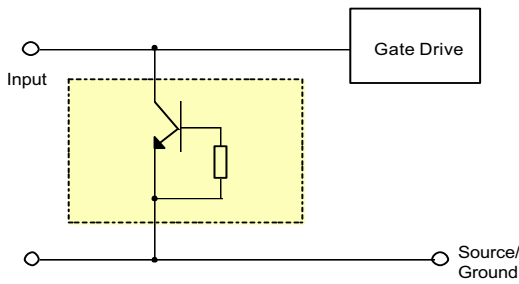
### Terms



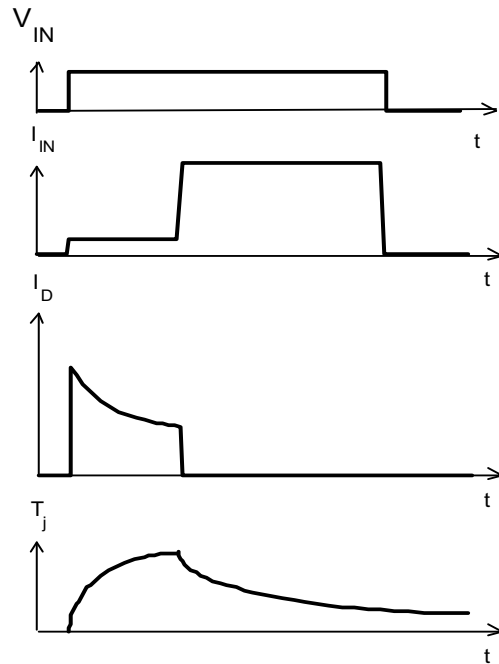
### Inductive and overvoltage output clamp



### Input circuit (ESD protection)



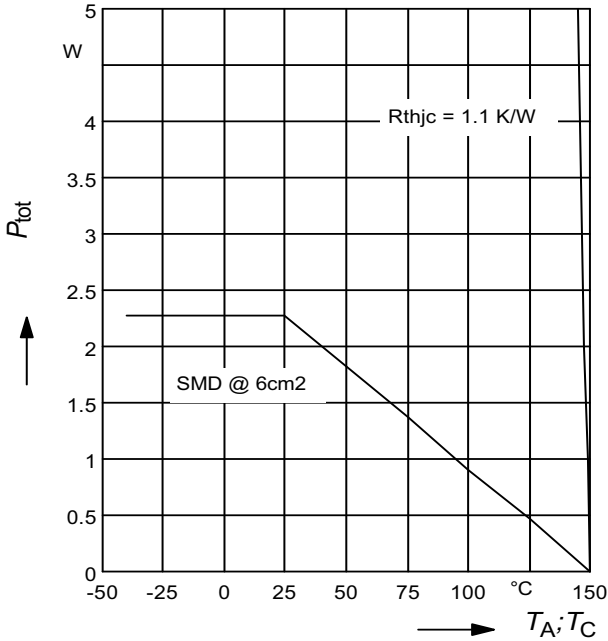
### Short circuit behaviour



**1 Maximum allowable power dissipation**

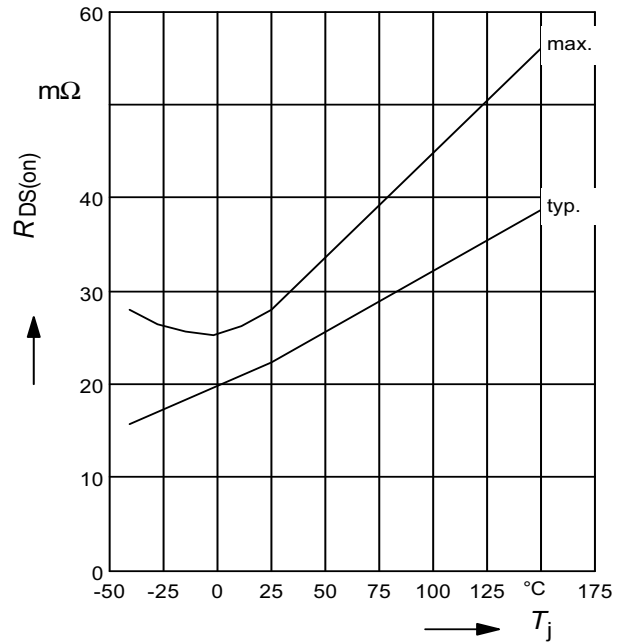
$P_{tot} = f(T_C)$  resp.

$P_{tot} = f(T_A) @ R_{thJA}=55 \text{ K/W}$



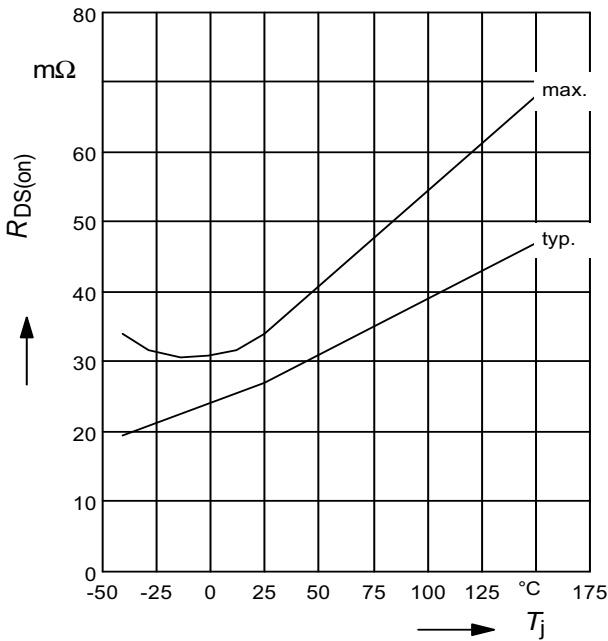
**2 On-state resistance**

$R_{ON} = f(T_j); I_D=12.6A; V_{IN}=10V$



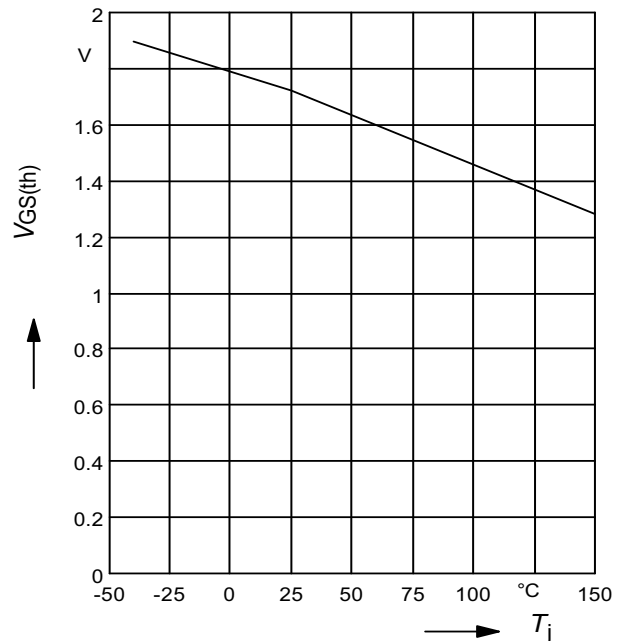
**3 On-state resistance**

$R_{ON} = f(T_j); I_D= 12.6A; V_{IN}=5V$



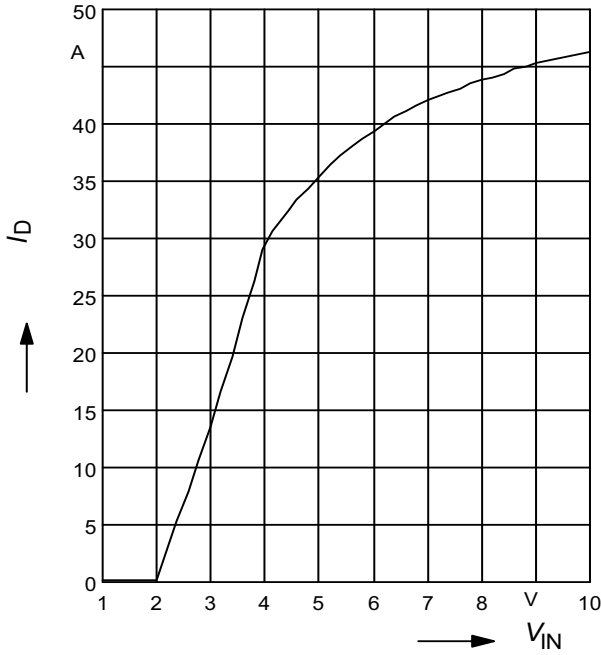
**4 Typ. input threshold voltage**

$V_{IN(th)} = f(T_j); I_D = 1.2 \text{ mA}; V_{DS} = 12V$



**5 Typ. transfer characteristics**

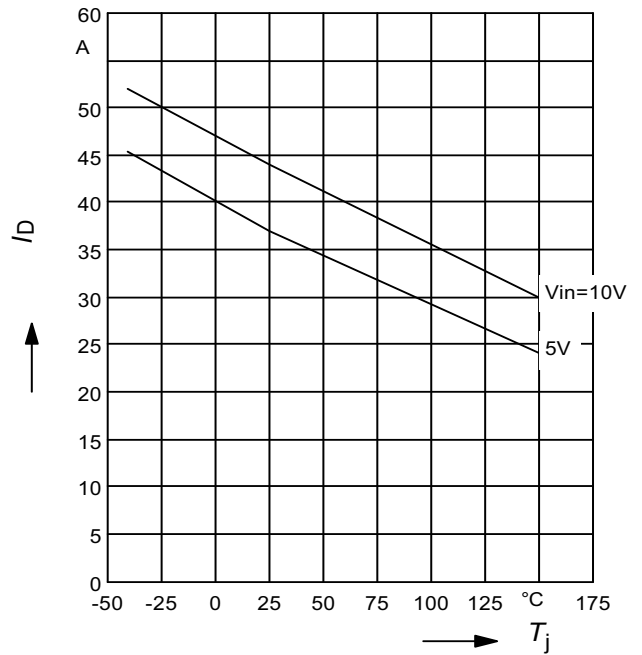
$I_D = f(V_{IN})$ ;  $V_{DS} = 12V$ ;  $T_{Jstart} = 25\text{ °C}$



**6 Typ. short circuit current**

$I_{D(lim)} = f(T_j)$ ;  $V_{DS} = 12V$

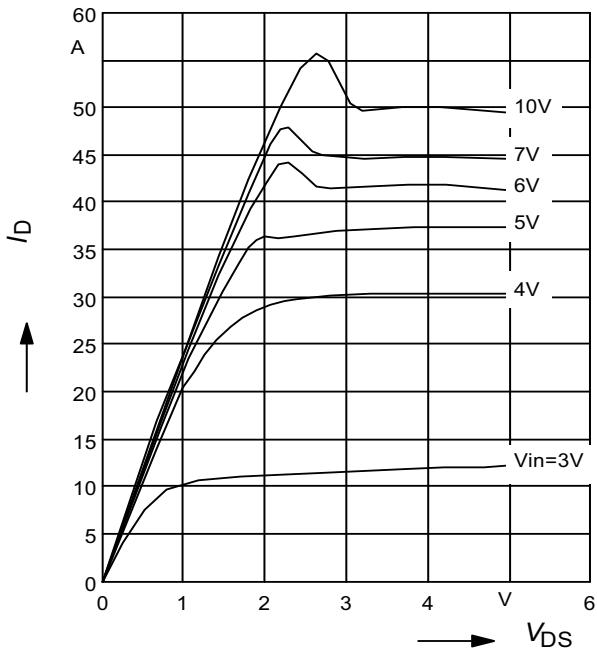
Parameter:  $V_{IN}$



**7 Typ. output characteristics**

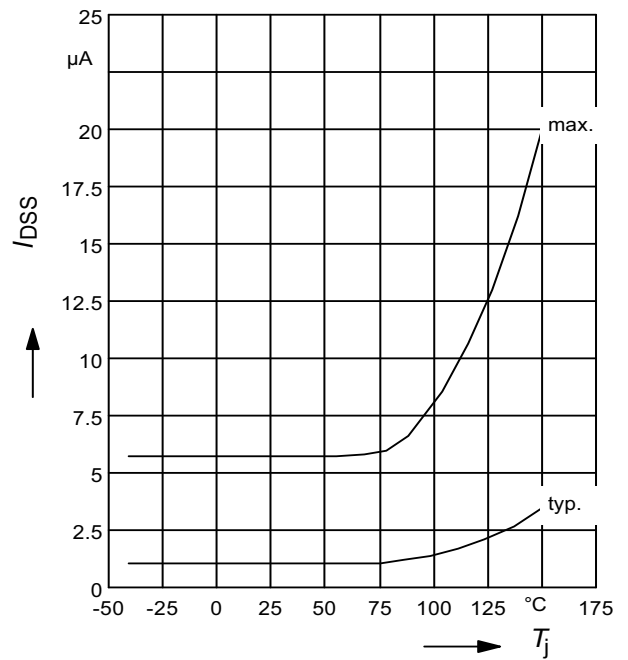
$I_D = f(V_{DS})$ ;  $T_{Jstart} = 25\text{ °C}$

Parameter:  $V_{IN}$



**8 Typ. off-state drain current**

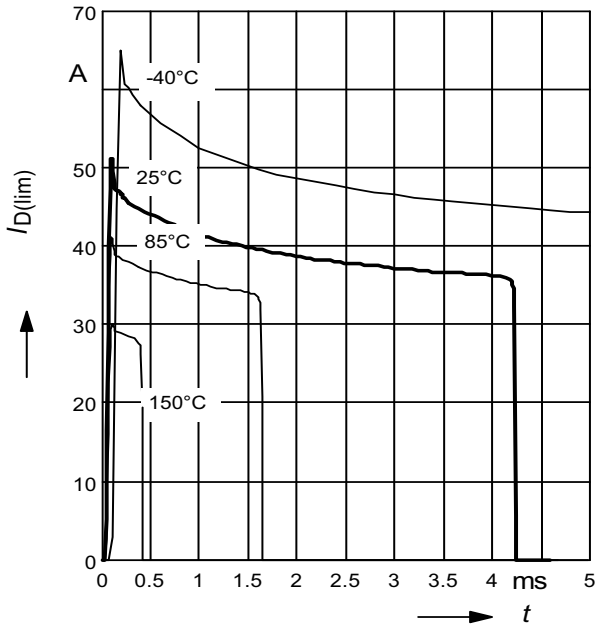
$I_{DSS} = f(T_j)$



**9 Typ. overload current**

$I_{D(lim)} = f(t)$ ,  $V_{bb}=12\text{ V}$ , no heatsink

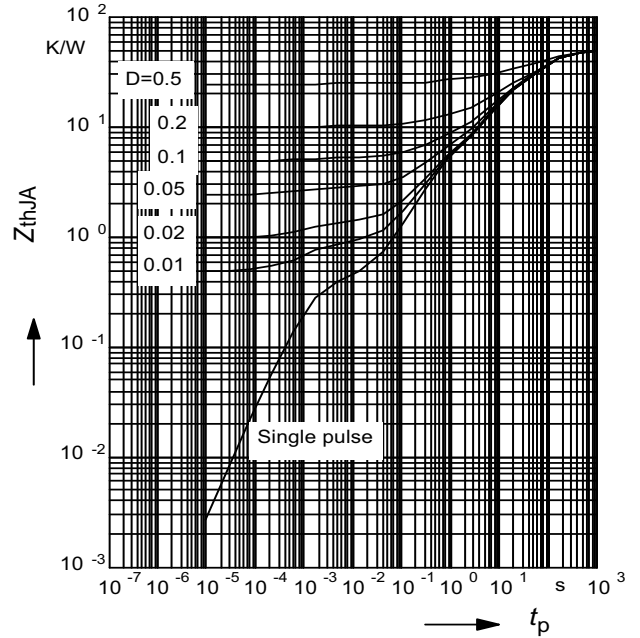
Parameter:  $T_{jstart}$



**10 Typ. transient thermal impedance**

$Z_{thJA} = f(t_p)$  @  $6\text{ cm}^2$  cooling area

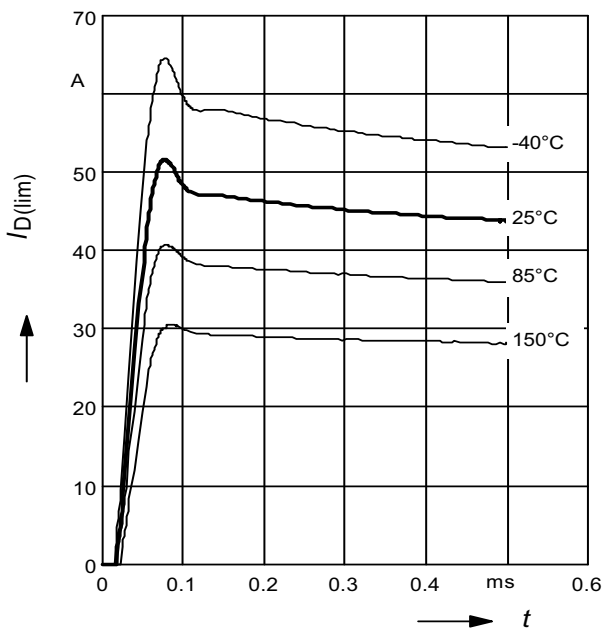
Parameter:  $D = t_p/T$



**11 Determination of  $I_{D(lim)}$**

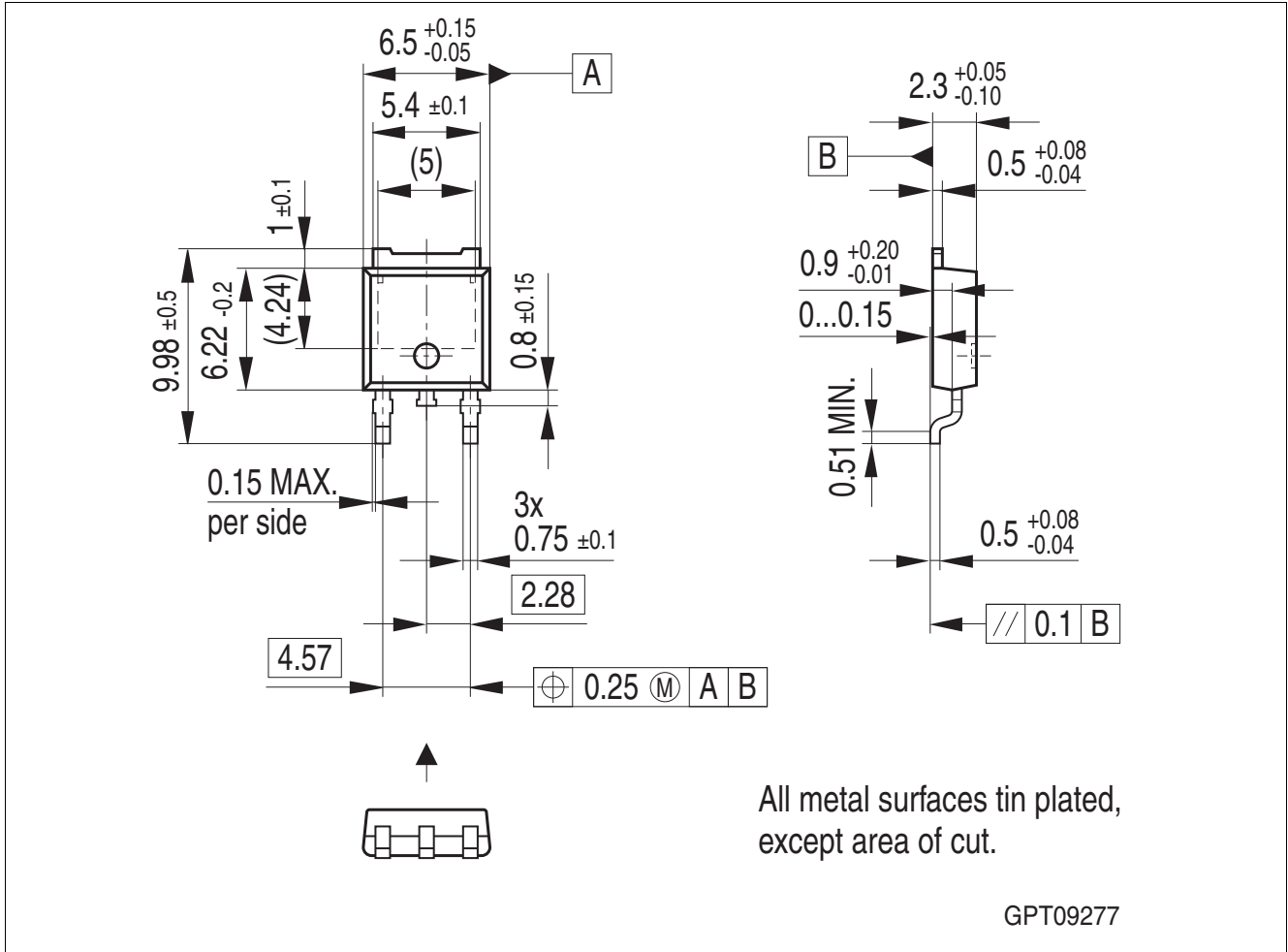
$I_{D(lim)} = f(t)$ ;  $t_m = 200\mu\text{s}$

Parameter:  $T_{jstart}$





# 1 Package Outlines



**Figure 1** PG-TO252-3-11 (Plastic Dual Small Outline Package) (RoHS-Compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

Please specify the package needed (e.g. green package) when placing an order

## 2 Revision History

Version	Date	Changes
Rev. 1.4	2013-03-07	page 2: - added footnote "Not subject to production test, specified by design" for chapter/table Maximum Ratings - added footnote "Not subject to prod. test, calculated ..." for parameter $P_{tot}$ - updated ESD HBM standard in chapter "Maximum Ratings" page 3: - updated test condition $I_D$ for parameter input threshold voltage $V_{IN(th)}$ - added footnote "Not subject to production test, calculated..." to the parameter Nominal load current $I_{D(nom)}$ , $I_{D(ISO)}$
Rev. 1.3	2006-12-22	released automotive green and robust version (BTS) Package parameter (humidity and climatic) removed in Maximum ratings
Rev. 1.2	2006-12-11	AEC icon added RoHS icon added Green product (RoHS-compliant) added to the feature list Package information updated to green Green explanation added
Rev. 1.1	2006-08-08	released non automotive green version (ITS)
Rev. 1.0	2004-03-05	released production version

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